

### SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

# SB80W06T — Schottky Barrier Diode (Twin Type • Cathode Common)

### 60V, 8A Rectifier

#### **Applications**

· High frequency rectification (switching regulators, converters, choppers)

#### **Features**

- Low forward voltage (VF max=0.6V)
- · Low switching noise
- · Halogen free compliance

- · Fast reverse recovery time
- · High reliability due to highly reliable planar structure

#### **Specifications**

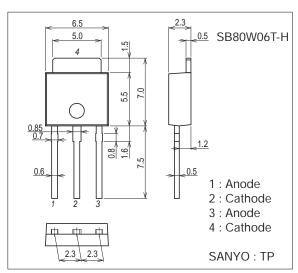
#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>		60	V
Nonrepetitive Peak Reverse Surg	ge Voltage VRSM		66	V

Continued on next page.

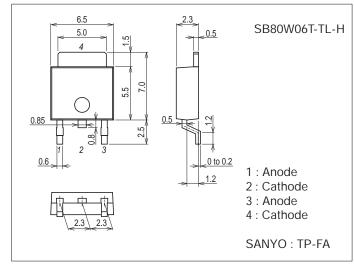
#### **Package Dimensions**

unit: mm (typ) 7518-001



#### Package Dimensions

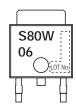
unit: mm (typ) 7003-002



#### **Product & Package Information**

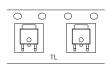
- Package : TP
- JEITA, JEDEC: SC-64, TO-251, SOT-553, DPAK
- Minimum Packing Quantity: 500 pcs./bag

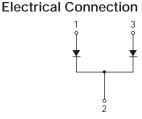
#### Marking (TP, TP-FA)



- Package: TP-FA
- JEITA, JEDEC: SC-63, TO-252, SOT-428, DPAK
- Minimum Packing Quantity: 700 pcs./reel

#### Packing Type (TP-FA): TL





#### **SANYO Semiconductor Co., Ltd.**

http://www.sanyosemi.com/en/network/

#### **SB80W06T**

#### Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Average Output Current	I <sub>O</sub> *2	50Hz resistive load, sine wave Tc=130°C	4	А
Average Output Current	I <sub>O</sub> *1	50Hz resistive load, sine wave Tc=83°C	8	Α
Surge Forward Current	I <sub>FSM</sub>	50Hz sine wave, 1 cycle	40	Α
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Note) \*1. Indicates the total value

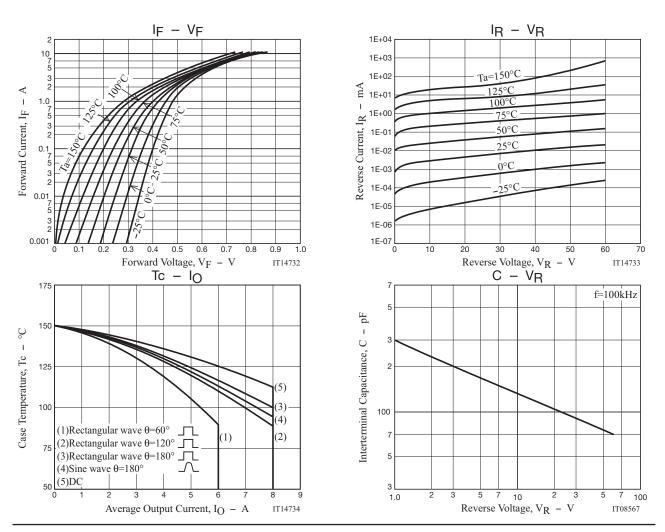
#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Syllibol	Conditions	min	typ	max	Offic	
Reverse Voltage	VR	I <sub>R</sub> =1mA, Tj=25°C *2	60			V	
Forward Voltage	VF	I <sub>F</sub> =3.0A, Tj=25°C *2			0.6	V	
Reverse Current	IR	V <sub>R</sub> =30V, Tj=25°C *2			0.1	mA	
Interterminal Capacitance	С	V <sub>R</sub> =10V, Tj=25°C *2		130		pF	
Transient Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC		6		°C/W	

Note) \*2. Value per element

#### **Ordering Information**

Device	Package	Shipping	memo
SB80W06T-H	TP	500pcs./bag	Pb Free and Halogen Free
SB80W06T-TL-H	TP-FA	700pcs./reel	Pb Fiee and Halogen Fiee



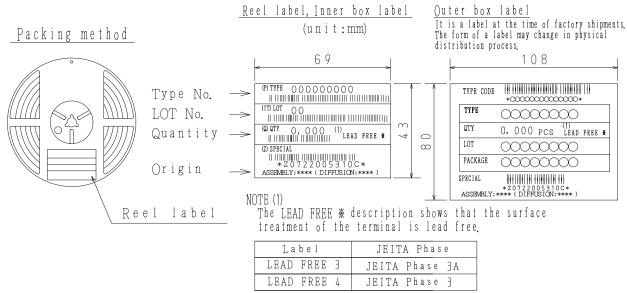
<sup>\*2.</sup> Value per element

#### **Taping Specification**

#### SB80W06T-TL-H

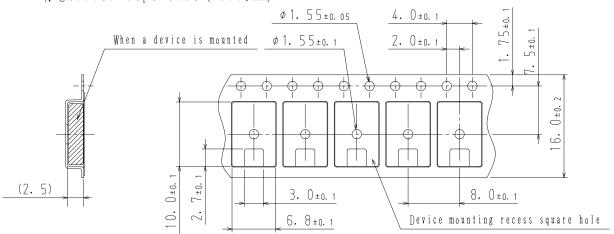
Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2, 100	12, 600	3 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210

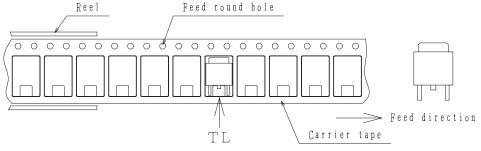


#### Taping configuration

1. Carrier tape size (unit:mm)



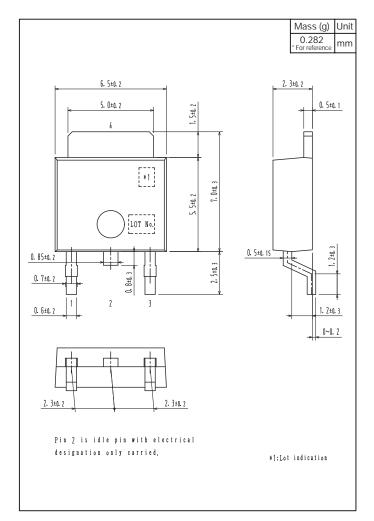
7. Device placement direction

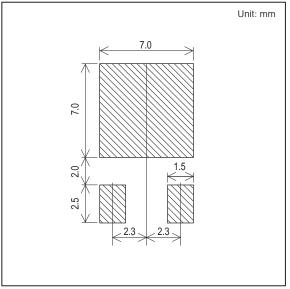


Those with one electrode terminal on the feed hole side · · · · · · TL

#### Outline Drawing SB80W06T-TL-H

#### Land Pattern Example



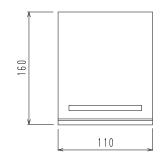


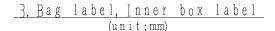
## Bag Packing Specification SB80W06T-H

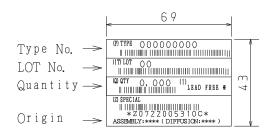
#### 1. Packing Format

Package Name	Maximum Number of devices contained (pcs)				
1 4 4 11 4 8 4 11 4 11 11	Bag	Inner box	Outer box		
TP		B-1	A-1	A-2	
1 1	500	10,000	50,000	30,000	
		Packing fo	ormat (Dimensions:mm (external))		
		Inner box	Outer box		
		B-1	A-1	A-2	
		445×225×55	470×250×300	470×250×190	

## 2. Bag dimensions (unit:mm)





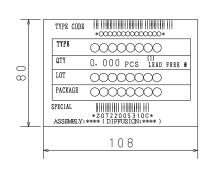


## 4. Outer box label (unit:mm)

It is a label at the time of factory shipments, The form of a label may change in physical distribution process,

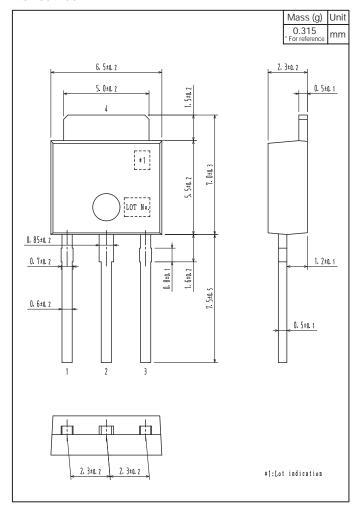


Label			JEITA Phase
LEAD	FREE	3	JEITA Phase 3A
LEAD	FREE	4	JEITA Phase 3



### **Outline Drawing**

SB80W06T-H



- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc., please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of September, 2012. Specifications and information herein are subject to change without notice.